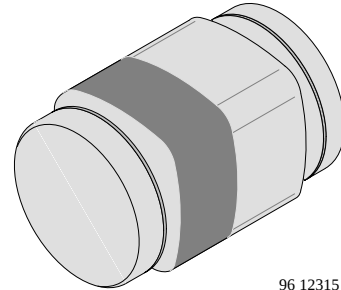




# Schottky Barrier Diodes

## Features

- Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- Low forward voltage drop
- Very low switching time



96 12315

## Applications

General purpose and switching  
Schottky barrier diode  
HF-Detector  
Protection circuit  
Diode for low currents with a low supply voltage  
Small battery charger  
Power supplies  
DC / DC converter for notebooks

## Absolute Maximum Ratings

 $T_j = 25^\circ\text{C}$ 

| Parameter                       | Test Conditions | Type   | Symbol    | Value      | Unit             |
|---------------------------------|-----------------|--------|-----------|------------|------------------|
| Reverse voltage                 |                 | BAS381 | $V_R$     | 40         | V                |
|                                 |                 | BAS382 | $V_R$     | 50         | V                |
|                                 |                 | BAS383 | $V_R$     | 60         | V                |
| Peak forward surge current      | $t_p=1\text{s}$ |        | $I_{FSM}$ | 500        | mA               |
| Repetitive peak forward current |                 |        | $I_{FRM}$ | 150        | mA               |
| Forward current                 |                 |        | $I_F$     | 30         | mA               |
| Junction temperature            |                 |        | $T_j$     | 125        | $^\circ\text{C}$ |
| Storage temperature range       |                 |        | $T_{stg}$ | -65...+150 | $^\circ\text{C}$ |

## Maximum Thermal Resistance

 $T_j = 25^\circ\text{C}$ 

| Parameter        | Test Conditions             | Symbol     | Value | Unit |
|------------------|-----------------------------|------------|-------|------|
| Junction ambient | on PC board 50mmx50mmx1.6mm | $R_{thJA}$ | 320   | K/W  |

## Electrical Characteristics

 $T_j = 25^\circ\text{C}$ 

| Parameter         | Test Conditions                   | Type | Symbol | Min | Typ | Max | Unit |
|-------------------|-----------------------------------|------|--------|-----|-----|-----|------|
| Forward voltage   | $I_F=0.1\text{mA}$                |      | $V_F$  |     |     | 330 | mV   |
|                   | $I_F=1\text{mA}$                  |      | $V_F$  |     |     | 410 | mV   |
|                   | $I_F=15\text{mA}$                 |      | $V_F$  |     |     | 1   | V    |
| Reverse current   | $V_R=V_{Rmax}$                    |      | $I_R$  |     |     | 200 | nA   |
| Diode capacitance | $V_R=1\text{V}$ , $f=1\text{MHz}$ |      | $C_D$  |     |     | 1.6 | pF   |

### Characteristics ( $T_j = 25^\circ\text{C}$ unless otherwise specified)

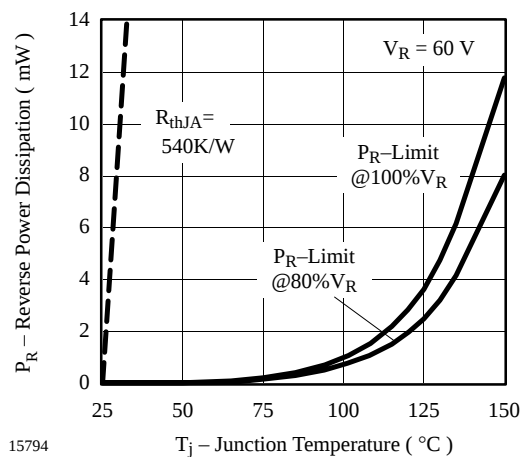


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature

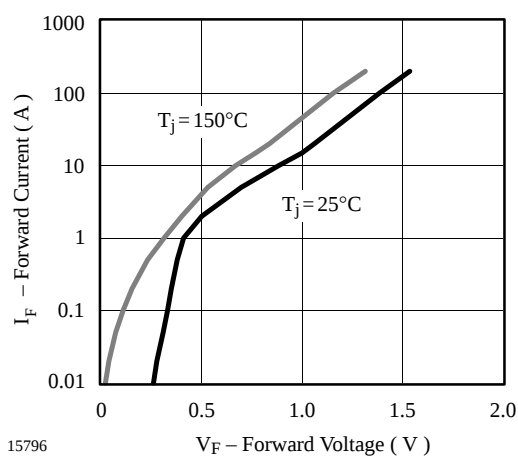


Figure 3. Forward Current vs. Forward Voltage

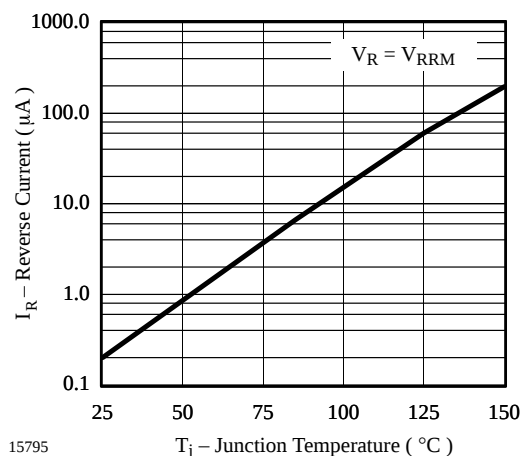


Figure 2. Reverse Current vs. Junction Temperature

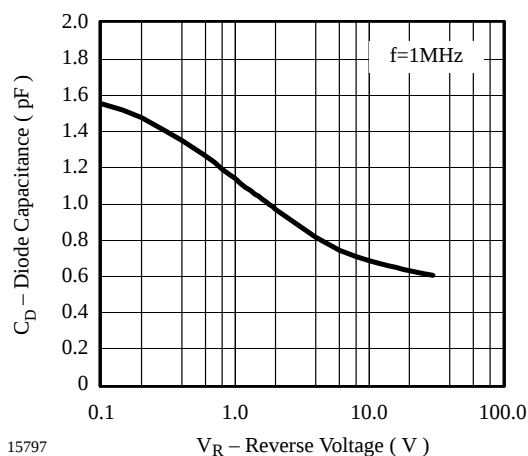


Figure 4. Diode Capacitance vs. Reverse Voltage

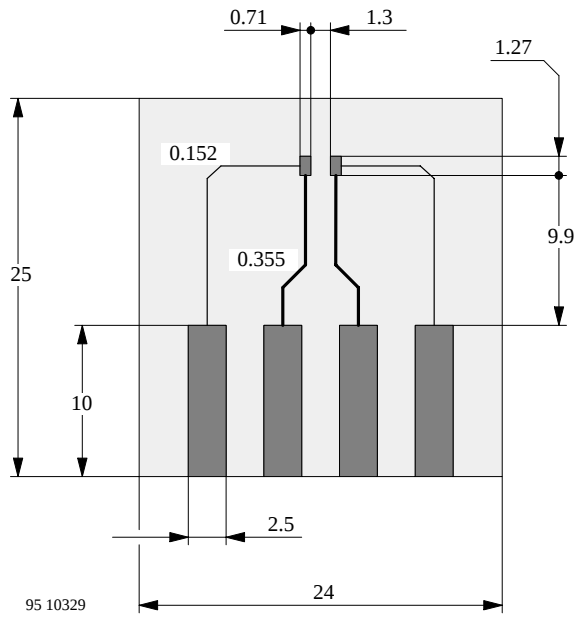


Figure 5. Board for  $R_{thJA}$  definition (in mm)

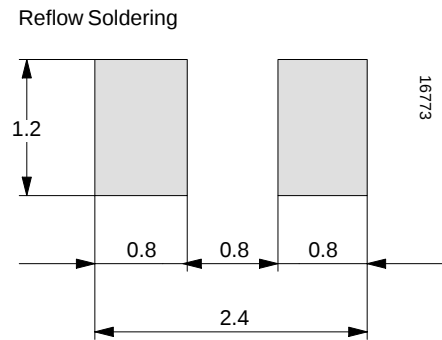


Figure 6. Recommended foot pads (in mm)

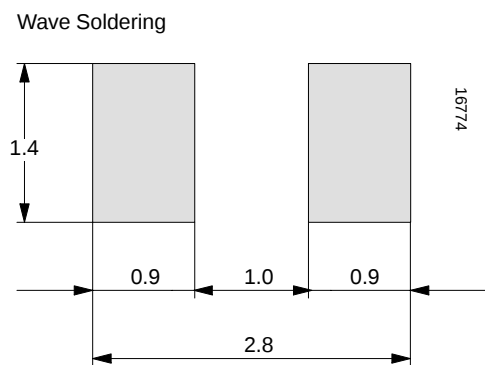
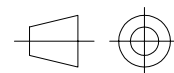
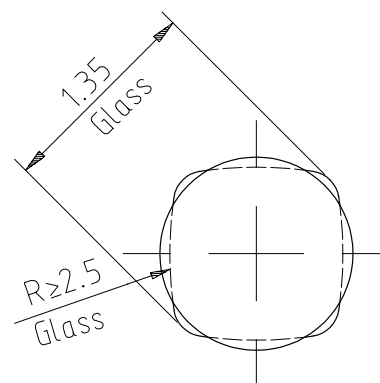
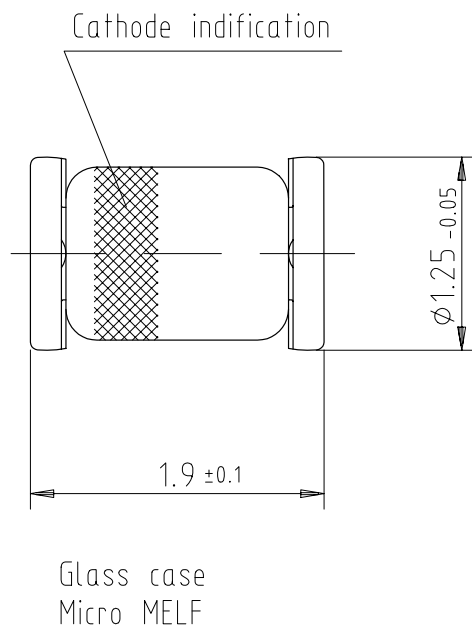


Figure 7. Recommended foot pads (in mm)

## Dimensions in mm



96 12072

technical drawings  
according to DIN  
specifications



### Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems  
with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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